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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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### DATA SHEET



## MOS FIELD EFFECT TRANSISTOR

## Phase-out/Discontinued

## μ **ΡΑ1704**

### SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

#### DESCRIPTION

This  $\mu$ PA1704 is N-Channel MOS Field Effect Transistor designed for power management applications and Li-ion battery application.

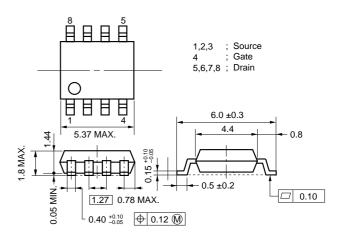
#### FEATURES

- 2.5-V gate drive and low on-resistance  $\label{eq:RDS(on)1} \begin{array}{l} \text{RDS(on)1} = 13 \ \text{m}\Omega \ \text{MAX}. \ (\text{VGs} = 4.0 \ \text{V}, \ \text{ID} = 5.0 \ \text{A}) \\ \ \text{RDS(on)2} = 16 \ \text{m}\Omega \ \text{MAX}. \ (\text{VGs} = 2.5 \ \text{V}, \ \text{ID} = 5.0 \ \text{A}) \end{array}$
- Low Ciss : Ciss = 2700 pF TYP.
- Built-in G-S protection diode
- Small and surface mount package (Power SOP8)

#### **ORDERING INFORMATION**

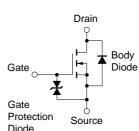
PART NUMBER	PACKAGE
μΡΑ1704G	Power SOP8

#### PACKAGE DRAWING (Unit : mm)



#### ABSOLUTE MAXIMUM RATINGS (TA = 25°C, All terminals are connected.)

Drain to Source Voltage (VGs = 0 V)	VDSS	30	V
Gate to Source Voltage (VDS = 0 V)	Vgss ±12		V
Drain Current (DC)	D(DC)	±10	А
Drain Current (pulse) <sup>Note1</sup>	D(pulse)	±40	А
Total Power Dissipation $(T_A = 25^{\circ}C)^{Note2}$	Рт	2.0	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	–55 to + 150	°C



EQUIVALENT CIRCUIT

**Notes 1.** PW  $\leq$  10  $\mu$ s, Duty Cycle  $\leq$  1 %

2. Mounted on ceramic substrate of 1200 mm<sup>2</sup> x 0.7 mm

**Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

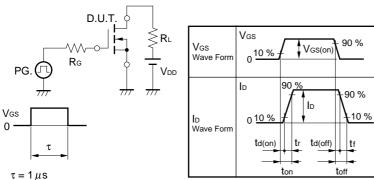
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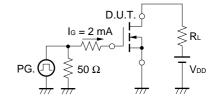
#### ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C, All terminals are connected.)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain to Source On-state Resistance	RDS(on)1	Vgs = 4.0 V, Id = 5.0 A		9.8	13	mΩ
	RDS(on)2	V <sub>GS</sub> = 2.5 V, I <sub>D</sub> = 5.0 A		12	16	mΩ
Gate to Source Cut-off Voltage	VGS(off)	Vds = 10 V, Id = 1 mA	0.5	0.8	1.5	V
Forward Transfer Admittance	y <sub>fs</sub>	Vds = 10 V, Id = 5.0 A	10	25		S
Drain Leakage Current	DSS	Vds = 30 V, Vgs = 0 V			10	μA
Gate to Source Leakage Current	lgss	$V_{GS} = \pm 12 \text{ V}, V_{DS} = 0 \text{ V}$			±10	μA
Input Capacitance	Ciss	Vds = 10 V		2700		pF
Output Capacitance	Coss	V <sub>G</sub> s = 0 V		880		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		400		pF
Turn-on Delay Time	td(on)	I <sub>D</sub> = 5.0 A		25		ns
Rise Time	tr	$V_{GS(on)} = 4.0 V$		95		ns
Turn-off Delay Time	td(off)	V <sub>DD</sub> = 15 V		235		ns
Fall Time	tr	R <sub>G</sub> = 10 Ω		200		ns
Total Gate Charge	QG	ID = 10 A		38		nC
Gate to Source Charge	QGS	VDD = 24 V		3.3		nC
Gate to Drain Charge	Q <sub>GD</sub>	V <sub>GS</sub> = 4.0 V		15		nC
Body Diode Forward Voltage	V <sub>F(S-D)</sub>	IF = 10 A, VGS = 0 V		0.8		V
Reverse Recovery Time	tır	IF = 10 A, VGs = 0 V		48		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/ μs		53		nC

#### **TEST CIRCUIT 1 SWITCHING TIME**



TEST CIRCUIT 2 GATE CHARGE





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Forward Transfer Admittance

|yfs

Drain to Source On-state Resistance -  $m\Omega$ 

RDS(on) -0 1

ID - Drain Current - A

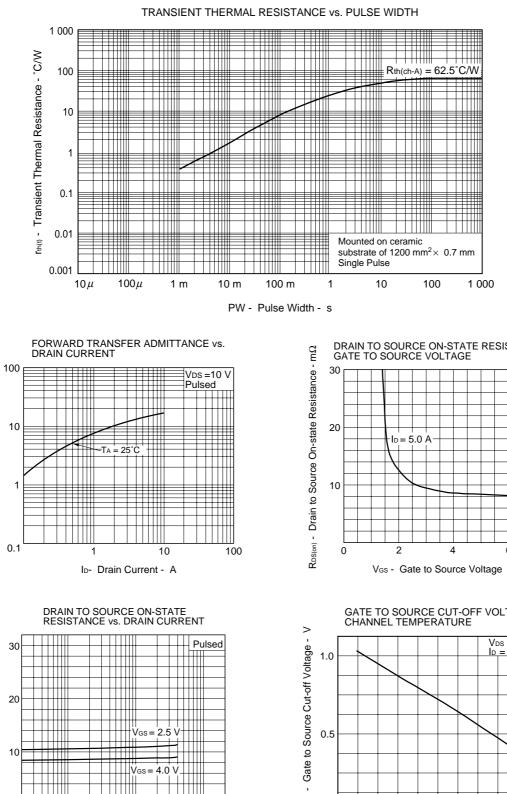
10

100

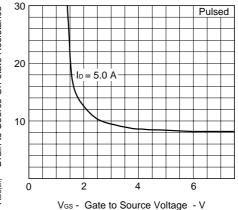
# Phase-out/Discontinued

μ PA1704

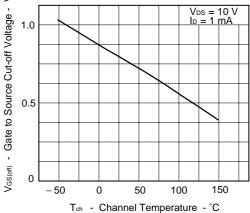
TYPICAL CHARACTERISTICS ( $T_A = 25^{\circ}C$ )



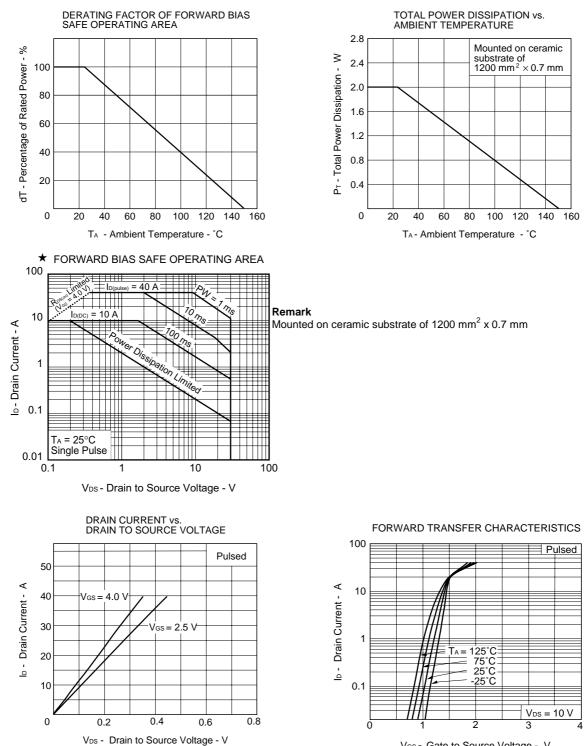
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



GATE TO SOURCE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



Data Sheet D12908EJ2V0DS

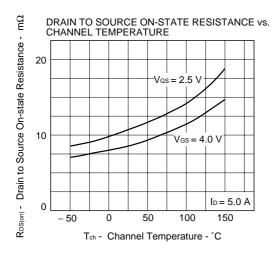


Vgs - Gate to Source Voltage - V

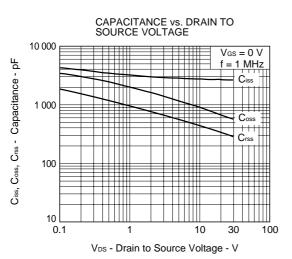
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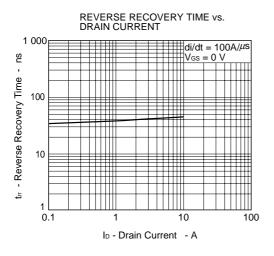
μ PA1704

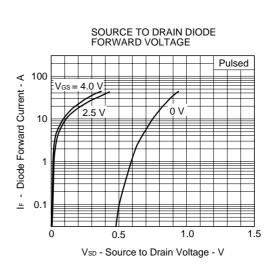
Phase-out/Discontinued

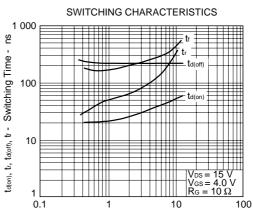


NEC

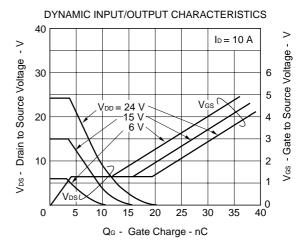








ID - Drain Current - A



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